

JAN2N6051

JAN2N6051 Information

Heisener.com	 JAN2N6051 Microsemi Corporation Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single TRANS PNP DARL 80V 12A TO-3 TO-3 For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



JAN2N6051 Specifications

Manufacturer Part Number	JAN2N6051	
Manufacturer	Microsemi Corporation	
Category	Discrete Semiconductor Products	
	Transistors - Bipolar (BJT) - Single	
Package	TO-3	
Series	Military, MIL-PRF-19500/501	
Transistor Type	PNP - Darlington	
Current - Collector (Ic) (Max)	12A	
Voltage - Collector Emitter Breakdown (Max)	80V	
Vce Saturation (Max) @ Ib, Ic	3V @ 120mA, 12A	
Current - Collector Cutoff (Max)	1mA	
DC Current Gain (hFE) (Min) @ Ic, Vce	1000 @ 6A, 3V	
Power - Max	150W	
Frequency - Transition	-	
Operating Temperature	-55°C ~ 175°C (TJ)	
Mounting Type	Through Hole	
Package / Case	ТО-3	
Supplier Device Package	TO-3 (TO-204AA)	
	Report errors?	

JAN2N6051 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.



If you have any question about JAN2N6051, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com